P. 01

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CERTIFICATE OF Applicant(s); Grant et al	TRANSMISSION BY FAC	SIMILE (37 CFR 1.8)	Docket No. BUR920040052US1				
Application No. 10/710,700	Filing Date 7/29/2004	Examiner Malsawma, Lalrinfamkim H	Group Art Unit Hmar 2823				
Invention: MODIFICAT	TION OF ELECTRICAL PROPE	ERTIES FOR SEMICONDUC	TOR WAFERS				
I hereby certify that this		est for Reconsideration (12 pa (Identify type of correspondence)					
is being facsimilo transmi	itted to the United States Patent	and Trademark Office (Fax. I	No. <u>571-273-8300</u>				
on [1/29/20	05						
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Grant et al.

Examiner: Malsawma, Lalrinfamkim Hmar

Scrial No.: 10/710,700

Art Unit: 2823

Filed: 07/29/2004

For: MOD

MODIFICATION OF ELECTRICAL PROPERTIES FOR SEMICONDUCTOR

WAFERS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Request for Reconsideration

Sir:

This Request for Reconsideration is in response to the Office Action mailed September 1, 2005.